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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT2185WP

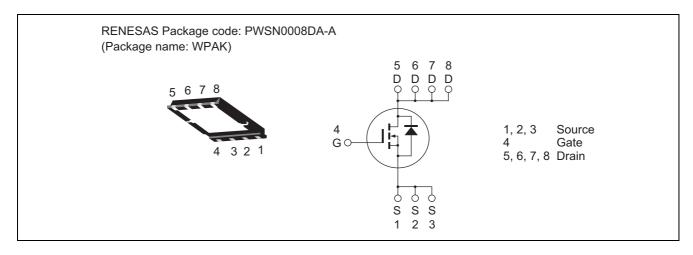
Silicon N Channel Power MOS FET Power Switching

REJ03G1744-0200 Rev.2.00 Nov 28, 2008

Features

- Low on-resistance
- Low drive current
- High density mounting

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

			(1a = 25 C)
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	150	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	10	А
Drain peak current	I _{D (pulse)} Note1	20	А
Body-drain diode reverse drain current	I _{DR}	10	Α
Body-drain diode reverse drain peak current	I _{DR (pulse)} Note1	20	Α
Avalanche current	I _{AP} Note3	10	Α
Avalanche energy	E _{AR} Note3	7.5	mJ
Channel dissipation	Pch Note2	20	W
Channel to case thermal impedance	θch-c	6.25	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tc = 25°C
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C

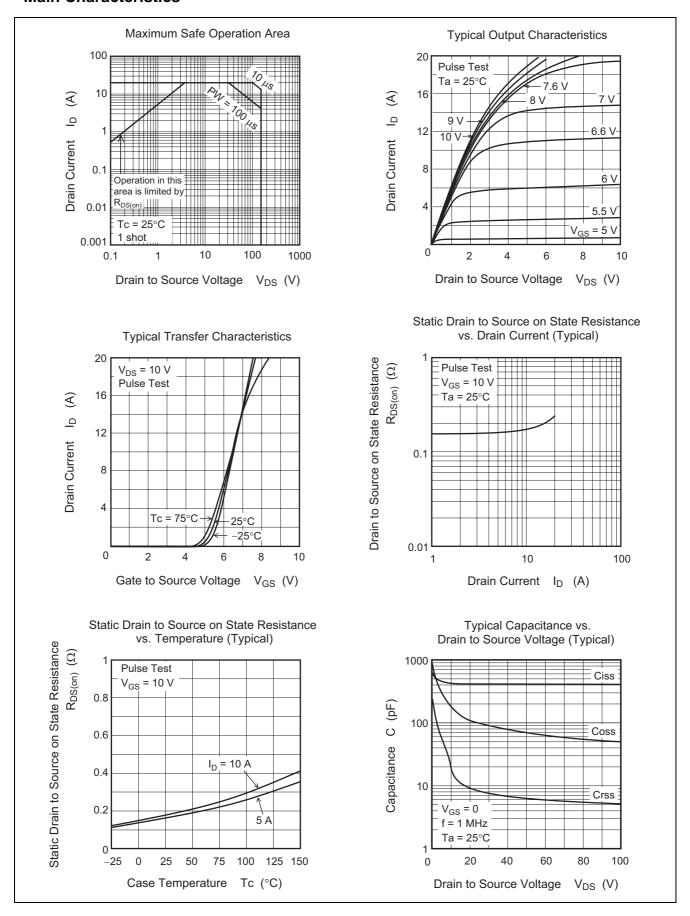
Electrical Characteristics

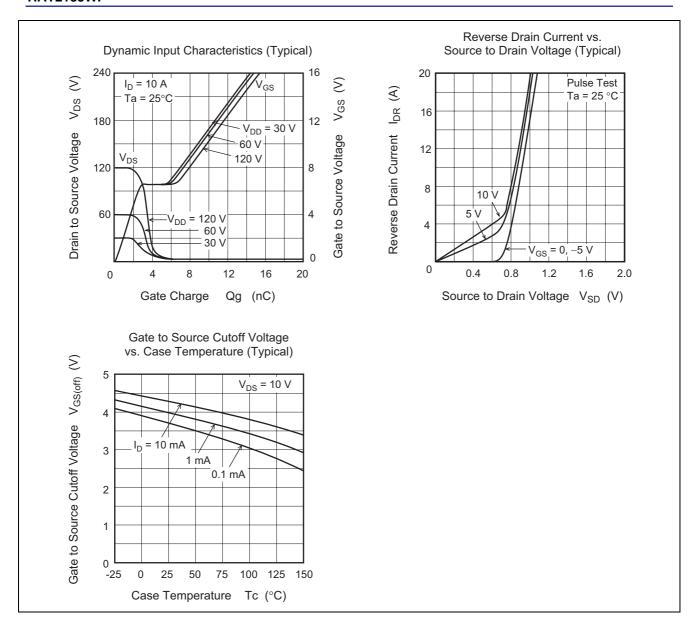
 $(Ta = 25^{\circ}C)$

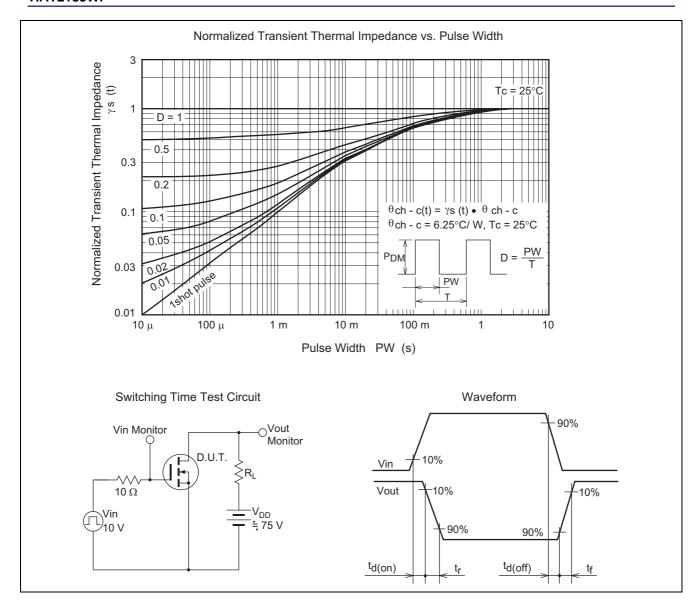
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	150	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 150 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Forward transfer admittance	yfs	4.0	6.5		S	$I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$
Static drain to source on state	R _{DS(on)}	_	0.17	0.19	Ω	$I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Input capacitance	Ciss		430	_	pF	V _{DS} = 25 V
Output capacitance	Coss		98		pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		8	_	pF	
Turn-on delay time	t _{d(on)}	_	24	_	ns	I _D = 5 A
Rise time	t _r	_	31	_	ns	V _{GS} = 10 V
Turn-off delay time	t _{d(off)}	_	43	_	ns	$R_L = 15 \Omega$
Fall time	t _f	_	8	_	ns	$Rg = 10 \Omega$
Total gate charge	Qg	_	9.7	_	nC	V _{DD} = 120 V
Gate to source charge	Qgs	_	2.7	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	3.9	_	nC	I _D = 10 A
Body-drain diode forward voltage	V_{DF}	_	0.9	1.4	V	$I_F = 10 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	90	_	ns	$I_F = 10 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

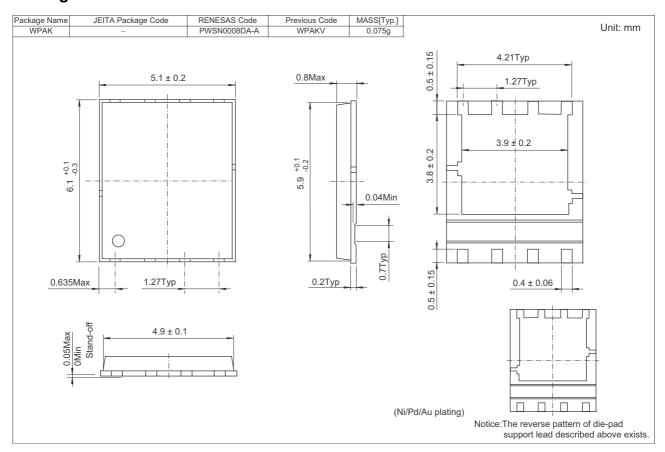
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2185WP-EL-E	2500 pcs, 3000 pcs	Taping

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